

# **GRF5115**

33.0 dBm Power-LNA™ Tuning Range: 0.1 – 2.7 GHz



#### **Features**

Reference: 5V/300mA/1.95GHz

Gain: 14.8 dB

OP1dB: 33.2 dBm

Drain Efficiency: 58%

OIP3: 43.0 dBm

Eval Board NF: 1.3 dB

Flexible Bias Voltage and Current

Process: GaAs pHEMT

### **Applications**

· High Efficiency Power Amplifier

Multi-stage LNA

Revision Date: 03/04/21

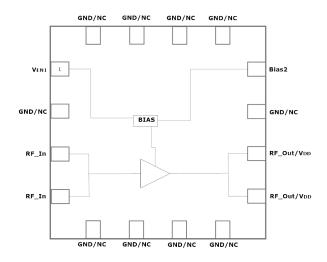
Linear Driver

### **Product Description**

GRF5115 is a high efficiency PA/Driver that delivers an OP1dB of 33 dBm with greater than 55% drain efficiency. It is tunable from 100 MHz up to 2.7 GHz with typical fractional bandwidths of 5 to 10%

The device can be biased with Vdd over a range from 2.7 to 5.0 volts and Iddq can be adjusted for optimal linearity and efficiency.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device sparameters.



3.0 x 3.0 mm QFN-16



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### **Absolute Ratings:**

Parameter	Symbol	Min.	Max.	Unit
Drain Voltage	V <sub>DD</sub>		5.5	V
Transient Average RF Input Power: (Load VSWR < 2:1; Duration: <1 hour)	P <sub>IN MAX</sub>		23.0	dBm
Operating Temperature (Package Heat Sink)	T <sub>AMB</sub>	-40	85	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P <sub>DISS MAX</sub>		2.0	W
Electrostatic Discharge:				
Charged Device Model: (TBD)	CDM	1500		V
Human Body Model: (TBD)	НВМ	250		V
Storage:				
Storage Temperature	$T_{STG}$	-65	150	°C
Moisture Sensitivity Level	MSL		1	-



#### Caution! ESD Sensitive Device



Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF5115 landing page: Manufacturing Note-MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

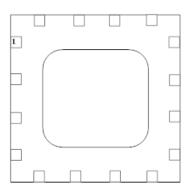
Link to manufacturing note



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### Pin Out (Top View)



#### Pin Assignments:

Pin	Name	Description	Note	
1	V <sub>EN1</sub>	Enable Voltage Input	Venable and series resistor set Iddo. Ven1 < =0.2 volts disables device. On- die pull-down resistor will turn the part off if this node is allowed to float	
2	NC	No Connect or Ground	No internal connection to die	
3	RF_In	RF Input	Pins 3-4 tied together on system board. R1 to ground is placed to limit self-biasing. The value of R1 also contributes to the device IDDQ	
4	RF_In	RF Input	Pins 3-4 tied together on system board. R1 to ground is placed to limit self-biasing. The value of R1 also contributes to the device IDDQ	
5	NC	No Connect or Ground	No internal connection to die	
6	NC	No Connect or Ground	No internal connection to die	
7	NC	No Connect or Ground	No internal connection to die	
8	NC	No Connect or Ground	No internal connection to die	
9	RF_Out/V <sub>DD</sub>	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.	
10	RF_Out/V <sub>DD</sub>	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.	
11	NC	No Connect or Ground	No internal connection to die	
12	Bias2	Bias Circuit Supply	Connect to VDD through external resistor	
13	NC	No Connect or Ground	No internal connection to die	
14	Bias1	Bias Circuit Ground	Consult application schematic	
<b>1</b> 5	NC	No Connect or Ground	No internal connection to die	
16	NC	No Connect or Ground	No internal connection to die	
KG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. R ommend multiple 8 mil vias beneath the package for optimal RF ar thermal performance. Refer to evaluation board top layer graphic o schematic page.	



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### **Nominal Operating Parameters:**

Parameter	Cymabal		Specification		Unit	Condition	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Target Performance (1.9 to 2.0 GHz Tune)						Bias: 5.0 V and 300 mA unless otherwise noted. (+25C)	
Test Frequency	FTEST		1.95		GHz		
Gain	S(2,1)	13.8	14.8	15.8	dB		
Noise Figure (Evaluation Board)	NF		1.3	1.6	dB		
Output 1dB Compression Point	OP1dB	31.5	33.0		dBm		
Drain Efficiency @ OP1dB	η		58.0		%		
Output Third Order Intercept Point	OIP3		43.0		dBm	12.0 dBm Р <sub>ОИТ</sub> per tone (1949 and 1951 MHz)	
Switching Rise Time	Trise		100		ns		
Switching Fall Time	TFALL		850		ns		
Quiescent Supply Current	IDDQ	200	300	400	mA	V <sub>DD</sub> = V <sub>EN1</sub> = 5.0V; M1: 22k ohms; M9: 100k ohms; R1: 15k ohms	
Enable Current	<b>I</b> ENABLE		0.5		mA		
Disabled Mode							
Supply Current (Leakage)	I <sub>DD</sub>		2.0		uA		
Thermal Data							
Thermal Resistance: (IR Scan Method)	Θјс		40		°C/W		
Channel Temperature @ +85C Reference (package heat sink)	Tchannel		145 (See note)		°C	V <sub>DD</sub> : 5.0 volts; I <sub>DDQ</sub> : 300 mA P <sub>DISS</sub> : 1.5 W; No RF	

Note: MTTF >10^6 hours for TCHANNEL < =170 degrees C.

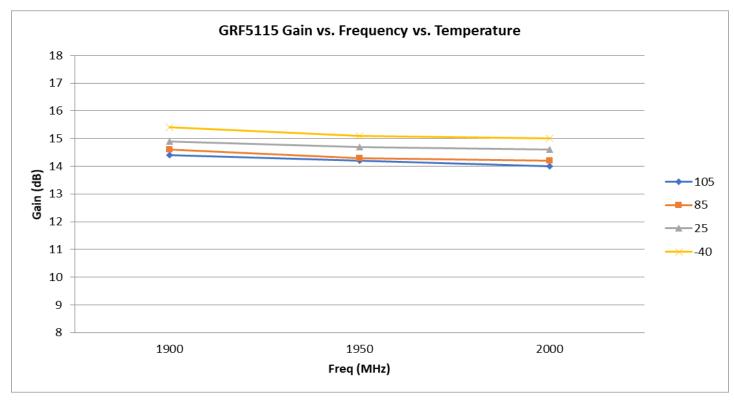


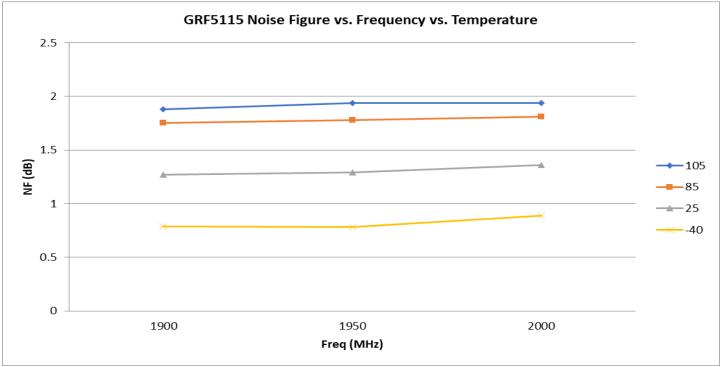
### Released

# **GRF5115**

33.0 dBm Power-LNA™ Tuning Range: 0.1 – 2.7 GHz

### **GRF5115** Evaluation Board Data: (1.9 to 2.0 GHz Tune)





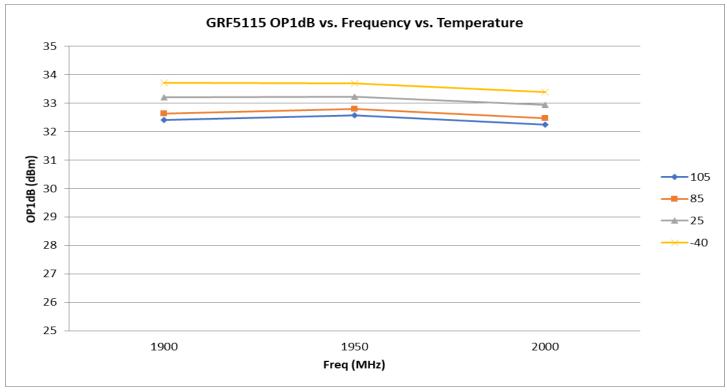


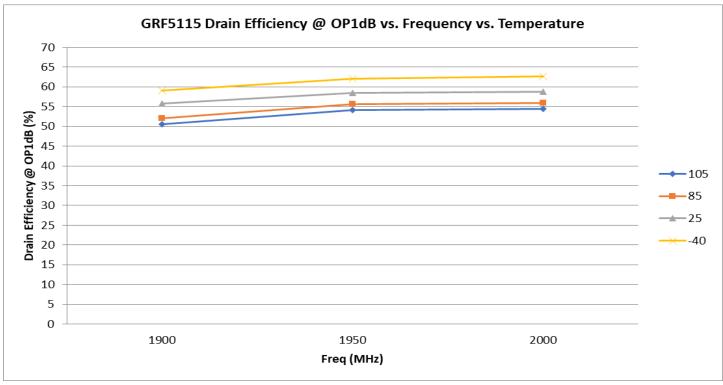
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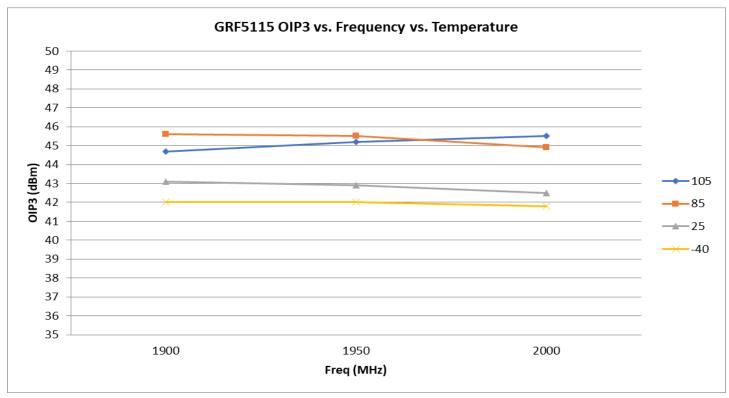


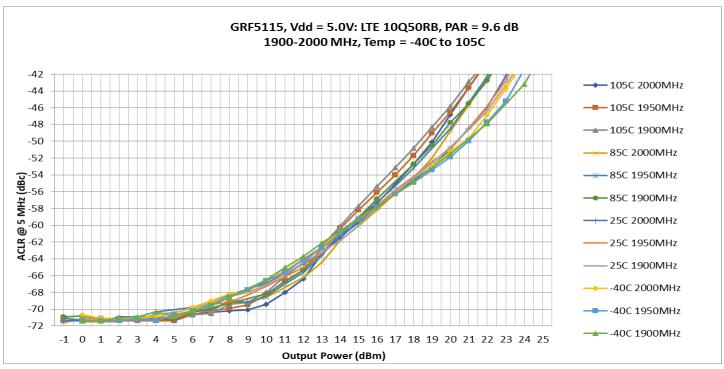


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### **GRF5115** Evaluation Board Data: (1.9 to 2.0 GHz Tune)



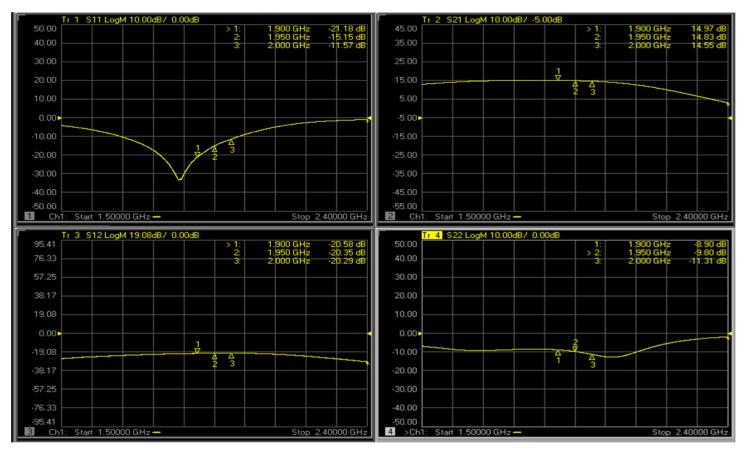


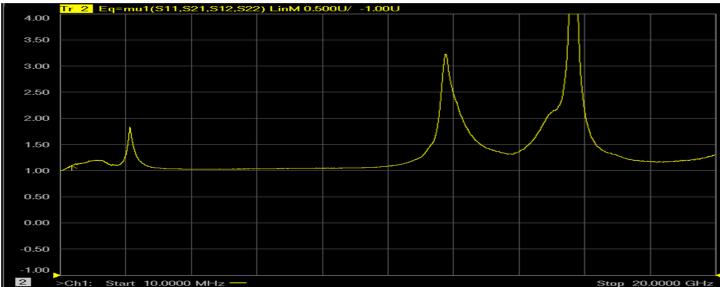


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### **GRF5115** Evaluation Board S-Pars: (1.9 to 2.0 GHz Tune)



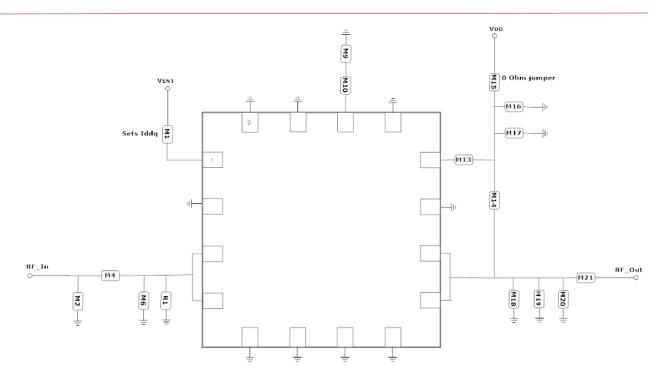


Note: Mu factor >= 1.0 implies unconditional stability.

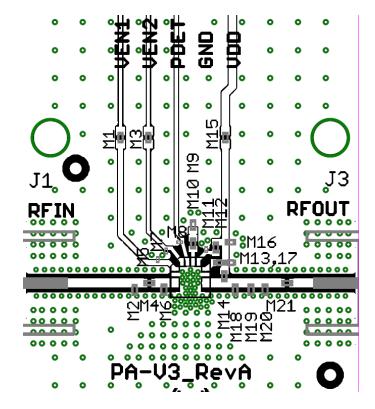


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**GRF5115** Application Schematic



GRF5115 Evaluation Board Assembly Drawing



# **GRF5115**

### 33.0 dBm Power-LNA™ Tuning Range: 0.1 - 2.7 GHz

#### **GRF5115** Evaluation Board BOM: (1.9 to 2.0 GHz Tune)

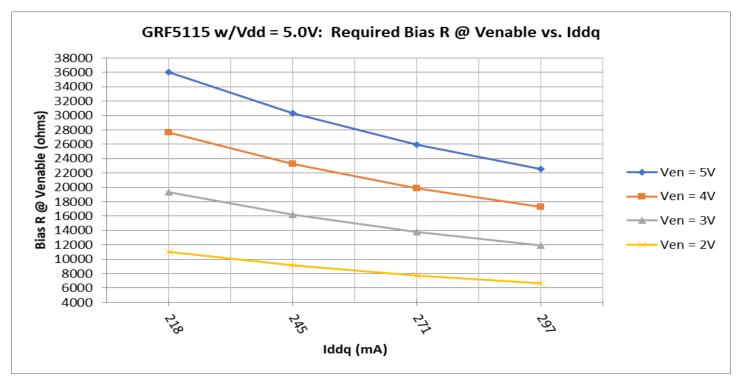
Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1 (See curves)	Resistor	Various	5%	Sets Iddq	0402	ok
M2	Inductor	Murata	LQP	6.2 nH	0402	ok
M4	Capacitor	Murata	GJM	1.5 pF	0402	ok
M6	Capacitor	Murata	GJM	3.9 pF	0402	ok
R1 (Adjacent M6)	Resistor	Various	5%	15k Ohm	0402	ok
M9	Resistor	Various	5%	100k Ohm	0402	ok
M10	Resistor	Various	_	0 Ohm	0402	ok
M13	Resistor	Various	5%	150 Ohm	0402	ok
M14	Inductor	Coilcraft	HP	8.2 nH	0402	ok
M15	Resistor	Various	_	0 Ohm	0402	ok
M16	Capacitor	Murata	GRM	0.1 uF	0402	ok
M17	Capacitor	Murata	GRM	100 pF	0402	ok
M18	Capacitor	Murata	GJM	3.9 pF	0402	ok
M19	DNP	-	_	_	0402	ok
M20	DNP	_	_	_	0402	ok
M21	Capacitor	Murata	GJM	15 pF	0402	ok
Evaluation board	PA-V3_RevA					

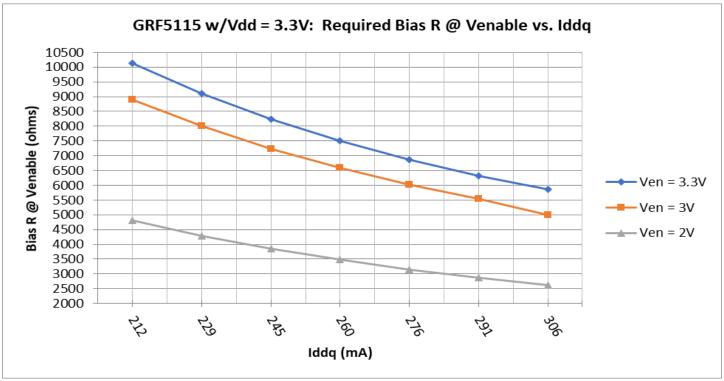


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GRF5115 Bias Resistor M1 Selection Curves; Note: R1: 15k ohms; M9: 100k ohms



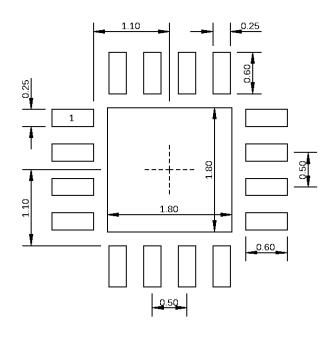




### Released

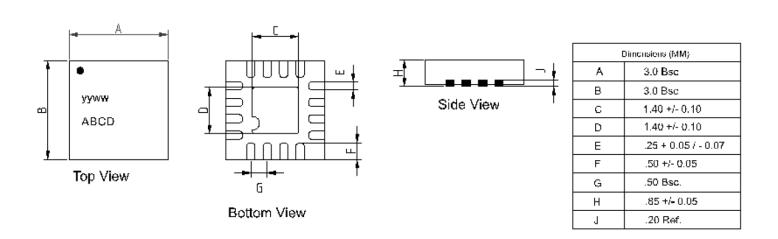
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Dimensions in millimeters

#### 3.0 mm QFN-16 Suggested PCB Footprint (Top View)



3.0 mm QFN-16 Package Dimensions



## **GRF5115**

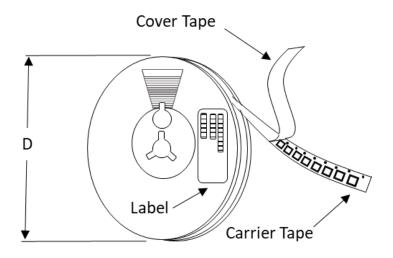
33.0 dBm Power-LNA™ Tuning Range: 0.1 – 2.7 GHz

#### Tape and Reel Information:

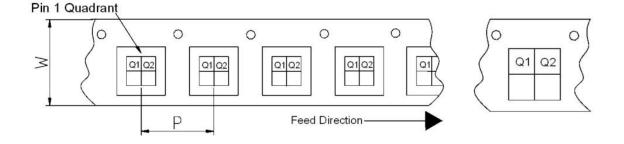
Revision Date: 03/04/21

Guerrilla RF's Tape and Reel specification complies with the Electronics Industries Association (EIA) standards for 'Embossed Carrier Tape of Surface Mount Components for Automatic Handling". Reference EIA-481. See the table on the following page for Tape and Reel specifications along with units per reel.

Devices are loaded with pins down into the carrier pocket with protective cover tape, wound into a plastic reel. Each reel will be packaged in a cardboard box. There will be product labels on the reel, the protective ESD bag and the outside surface of the box.



**Tape and Reel Packaging with Reel Diameter Noted (D)** 



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information



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#### Tape and Reel Specification and Device Package Information Table

Package		Carrier Tape			Reel			
Туре	Dimensions (mm)	Leads	Weight (mg)	Width (W) (mm)	Pocket Pitch (P) (mm)	Pin 1 Quad- rant	Diameter (D) (inches)	Units per Reel
QFN	2.0 x 2.0 x 0.50	12	7	8	4	Q1	7	2500
QFN	3.0 x 3.0 x 0.85	16	24	12	8	Q1	7	1500
DFN	1.5 x 1.5 x 0.45	6	4	8	4	Q1	7	2500
DFN	2.0 x 2.0 x 0.75	8	12	8	4	Q1	7	2500
LFM	3.5 x 3.5 x 0.75	See	TBD	12	8	Q2	7	1500
LFM	4.0 x 4.0 x 0.75	See note	TBD	12	8	Q2	7	1500

Note: Lead count may vary. Reference applicable product data sheet



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Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

Revision Date: 03/04/21

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